# **Dual Bias Resistor Transistor**

# NPN and PNP Silicon Surface Mount Transistors with Monolithic Bias Resistor Network

• High Current: I<sub>C</sub> = 500 mA max

• This is a Pb–Free Device

### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit	
Collector-Base Voltage	V <sub>(BR)CBO</sub>	50	Vdc	
Collector–Emitter Voltage	V <sub>(BR)CEO</sub>	50	Vdc	
Emitter-Base Voltage	V <sub>(BR)EBO</sub>	5.0	Vdc	
Collector Current – Continuous	I <sub>C</sub>	500	mAdc	

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation*	P <sub>D</sub>	285	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 to +150	°C

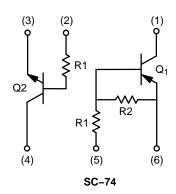
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

\*Total for both Transistors.



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### MARKING DIAGRAM



SC-74R 318AA Style 21



D10 = Specific Device Code

M = Date Code

= Pb-Free Package

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
IMD10AMT1G	SC-74R (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### **ELECTRICAL CHARACTERISTICS**

( $T_A$  = 25°C unless otherwise noted, common for  $Q_1$  and  $Q_2$ , – minus sign for  $Q_1(PNP)$  omitted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS			•	•
Collector–Base Breakdown Voltage ( $I_C = 50 \mu Adc$ , $I_E = 0 A$ )	V <sub>(BR)CBO</sub>	50	-	Vdc
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 1.0 mAdc, I <sub>B</sub> = 0 A)	V <sub>(BR)CEO</sub>	50	-	Vdc
Emitter–Base Breakdown Voltage ( $I_E = 50 \mu Adc$ , $I_C = 0 A$ )	$V_{(BR)EBO}$	5.0	-	Vdc
Collector–Base Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0 A)	I <sub>CBO</sub>	-	100	nA
	I <sub>EBO</sub>	- -	1.0 0.5	mA
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 15 Vdc, I <sub>B</sub> = 0 A)	I <sub>CEO</sub>	-	500	nA
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 25 Vdc, I <sub>B</sub> = 0 A)	I <sub>CES</sub>	-	100	nA
ON CHARACTERISTICS (Note 1)				
DC Current Gain $(V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}) \text{ Q1(PNP)} $ $(V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}) \text{ Q2(NPN)}$	h <sub>FE</sub>	68 100	_ 600	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1.0 mA)	V <sub>CE(sat)</sub>	-	0.3	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	-	0.2	Vdc
Output Voltage (off) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 0.25 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	4.9	-	Vdc
Input Resistor Q1(PNP) Q2(NPN)	R1	70 7.0	130 13	Ω kΩ
Resistor Ratio Q1(PNP) Q2(NPN)	R1/R2	0.008	0.012	

<sup>1.</sup> Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle < 2.0%.

## **TYPICAL CHARACTERISTICS (NPN)**

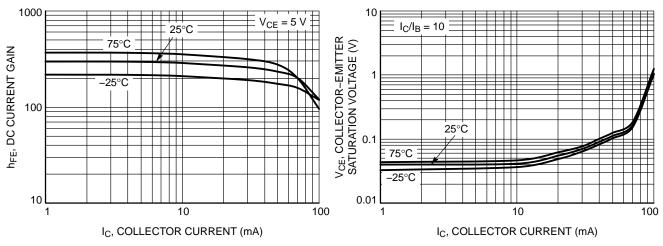


Figure 1. DC Current Gain

Figure 2. Collector-Emitter Saturation Voltage

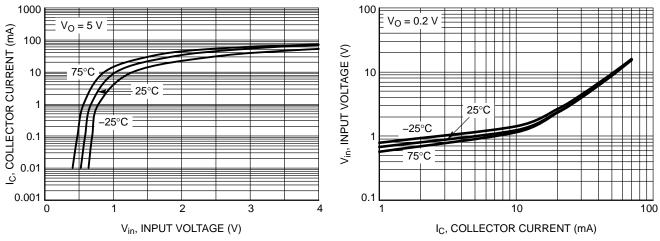


Figure 3. Output Current vs. Input Voltage

Figure 4. Input Voltage vs. Output Current

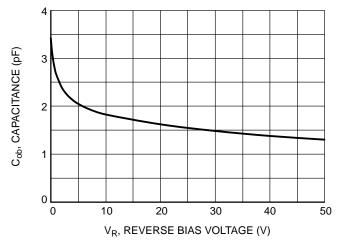


Figure 5. Output Capacitance

## **TYPICAL CHARACTERISTICS (PNP)**

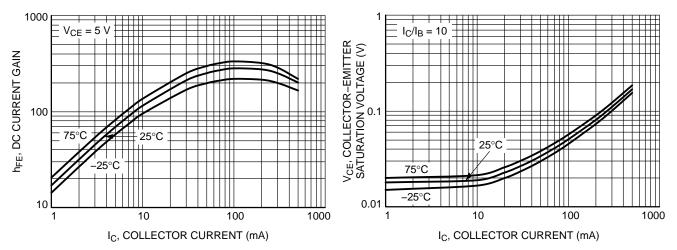


Figure 6. DC Current Gain

Figure 7. Collector-Emitter Saturation Voltage

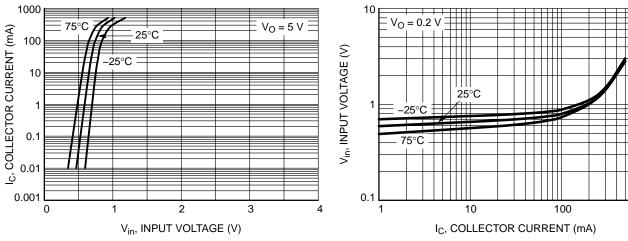


Figure 8. Output Current vs. Input Voltage

Figure 9. Input Voltage vs. Output Current

1000

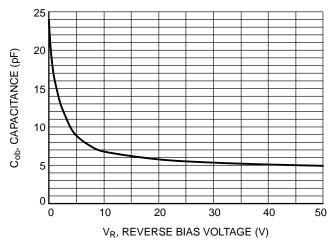
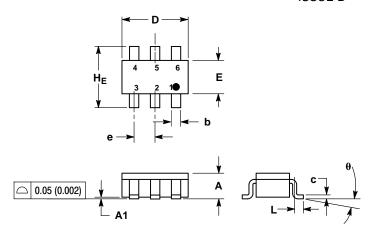


Figure 10. Output Capacitance

#### PACKAGE DIMENSIONS

### SC-74R CASE 318AA ISSUE B



#### NOTES:

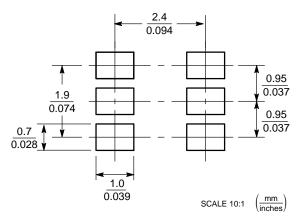
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
С	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
е	0.85	0.95	1.05	0.034	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
θ	0°	-	10°	0°	-	10°

#### STYLE 21:

- PIN 1. COLLECTOR 1 2. EMITTER 2 3. BASE 2

  - 4. COLLECTOR 2
  - 5. EMITTER 1 BASE 1
- **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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